

isc N-Channel MOSFET Transistor

20N15

• FEATURES

- Drain Current I_D= 20A@ T_C=25℃
- Drain Source Voltage-
 - : V_{DSS}= 150V(Min)
- · Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 0.075 \Omega (Max)$
- Fast Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

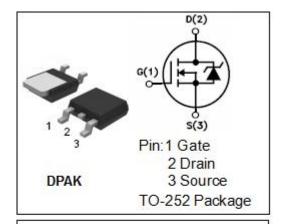
- Switching applications in power supplies
- Motor controls, high efficient DC to DC converters

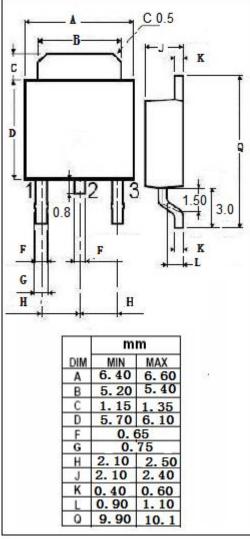
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	150	V
V _{GS}	Gate-Source Voltage-Continuous	±20	٧
I _D	Drain Current-Continuous	20	Α
I _{DM}	Drain Current-Single Plused	40	Α
P_D	Total Dissipation @T _C =25℃	90	W
Tj	Max. Operating Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature	-55~150	${\mathbb C}$



SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0. 6	°C/W





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• ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D =250μA	150	165		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =250μA	1.2	1.6	2.5	V
V _{SD}	Diode Forward On-voltage	I _S = 20A ;V _{GS} = 0			1.2	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 10A		0. 062	0.075	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =150V; V _{GS} = 0			1	μA
C _{iss}	Input Capacitance	V _{DS} =75V;		2500		
C _{rss}	Reverse Transfer capacitance	V _{GS} =0V;		68		pF
Coss	Output Capacitance	-		64		

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